# LIXYS

### DHG60I600HA

### **Sonic Fast Recovery Diode**

		advanced
$V_{RRM}$	=	600 V
l <sub>fav</sub>	=	60 A
t <sub>rr</sub>	=	35 ns

High Performance Fast Recovery Diode Low Loss and Soft Recovery Single Diode

### Part number DHG60I600HA



Package: TO-247

RoHS compliant

· Industry standard outline

• Epoxy meets UL 94V-0

Backside: cathode



#### Features / Advantages:

- Planar passivated chips
- Very low leakage current
- Very short recovery time
- Improved thermal behaviour
- Very low Irm-values
- Very soft recovery behaviour
- Avalanche voltage rated for reliable operation
- Soft reverse recovery for low EMI/RFI
  Low Irm reduces:
- Power dissipation within the diode
- Turn-on loss in the commutating switch

#### Applications:

- Antiparallel diode for high frequency
- switching devices
- Antisaturation diode
- Snubber diode
- Free wheeling diodeRectifiers in switch mode power
- supplies (SMPS)
- Uninterruptible power supplies (UPS)

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Fast Diode			Ratings				
Symbol	Definition	Conditions		min.	typ.	max.	Unit
	max. non-repetitive reverse blocki	ng voltage	$T_{VJ} = 25^{\circ}C$			600	V
	max. repetitive reverse blocking v	oltage	$T_{VJ} = 25^{\circ}C$			600	V
I <sub>R</sub>	reverse current, drain current	$V_{R} = 600 V$	$T_{VJ} = 25^{\circ}C$			200	μA
		$V_{R} = 600 V$	$T_{vJ} = 125^{\circ}C$			4	mA
V <sub>F</sub>	forward voltage drop	I <sub>F</sub> = 60 A	$T_{VJ} = 25^{\circ}C$			2.39	V
		I <sub>F</sub> = 120 A				3.30	V
		I <sub>F</sub> = 60 A	T <sub>vJ</sub> = 125°C			2.41	V
		I <sub>F</sub> = 120 A				3.50	V
I <sub>FAV</sub>	average forward current	$T_c = 85^{\circ}C$	T <sub>vJ</sub> = 150°C			60	A
		rectangular d = 0.5					
V <sub>F0</sub>	threshold voltage	and a darlar contra	T <sub>vJ</sub> = 150°C			1.20	V
r <sub>F</sub>	slope resistance } for power in	oss calculation only				19.5	mΩ
R <sub>thJC</sub>	thermal resistance junction to case	9				0.3	K/W
R <sub>thCH</sub>	thermal resistance case to heatsir	nk			0.25		K/W
P <sub>tot</sub>	total power dissipation		$T_c = 25^{\circ}C$			415	W
	max. forward surge current	t = 10 ms; (50 Hz), sine; $V_R = 0 V$	$T_{vJ} = 45^{\circ}C$			430	А
C	junction capacitance	$V_{R}$ = 400 V f = 1 MHz	$T_{VJ} = 25^{\circ}C$		47		pF
I <sub>RM</sub>	max. reverse recovery current		$T_{vJ} = 25^{\circ}C$		24		А
		$I_{\rm F} = 60  \text{A};  V_{\rm R} = 400  \text{V}$	T <sub>vJ</sub> = 125°C		tbd		A
t <sub>rr</sub>	reverse recovery time	di <sub>F</sub> /dt = 1200 A/μs	$T_{VJ} = 25^{\circ}C$		35		ns
		)	T <sub>vJ</sub> = 125°C		tbd		ns

IXYS reserves the right to change limits, conditions and dimensions.

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Package	Package TO-247			Ratings			
Symbol	Definition	Conditions	min.	typ.	max.	Unit	
I <sub>RMS</sub>	RMS current	per terminal			70	A	
T <sub>stg</sub>	storage temperature		-55	5	150	°C	
T <sub>vj</sub>	virtual junction temperature		-55	5	150	°C	
Weight				6		g	
M <sub>D</sub>	mounting torque		0.0	3	1.2	Nm	
F <sub>c</sub>	mounting force with clip		20	)	120	N	

#### Product Marking



#### Part number

- D = Diode
- H = Sonic Fast Recovery Diode
- G = extreme fast
- 60 = Current Rating [A] I = Single Diode
- 600 = Reverse Voltage [V]
- HA = TO-247AD(2)

Ordering	Part Number	Marking on Product	Delivery Mode	Quantity	Code No.
Standard	DHG60I600HA	DHG601600HA	Tube	30	510214

Similar Part	Package	Voltage class
DPH30IS600HI	ISOPLUS247 (2)	600
DSEP60-06A	TO-247AD (2)	600
DSEP60-06AT	TO-268AA (D3Pak) (2)	600

Equivalent Circuits for Simulation			* on die level	T <sub>vJ</sub> = 150 °C
	R₀	Fast Diode		
V <sub>0 max</sub>	threshold voltage	1.2		V
R <sub>0 max</sub>	slope resistance *	17		mΩ

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Sym.	Inches		Millim	eter
	min.	max.	min.	max.
А	0.185	0.209	4.70	5.30
A1	0.087	0.102	2.21	2.59
A2	0.059	0.098	1.50	2.49
D	0.819	0.845	20.79	21.45
Е	0.610	0.640	15.48	16.24
E2	0.170	0.216	4.31	5.48
е	0.430	BSC	10.92	BSC
L	0.780	0.800	19.80	20.30
L1	-	0.177	-	4.49
ØΡ	0.140	0.144	3.55	3.65
Q	0.212	0.244	5.38	6.19
S	0.242 BSC		6.14 BSC	
b	0.039	0.055	0.99	1.40
b2	0.065	0.094	1.65	2.39
b4	0.102	0.135	2.59	3.43
с	0.015	0.035	0.38	0.89
D1	0.515	-	13.07	-
D2	0.020	0.053	0.51	1.35
E1	0.530	-	13.45	-
ØP1	-	0.29	-	7.39

D2

D1

Ø P1

4



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